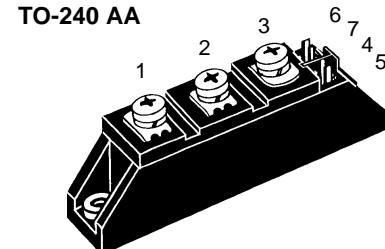


# High Voltage Thyristor Module

## High Voltage Thyristor/Diode Modules

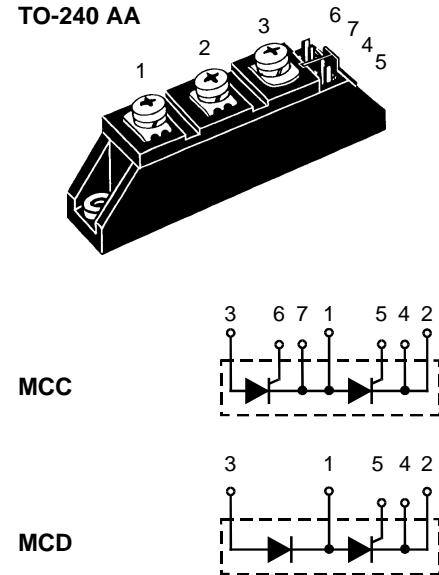
**I<sub>TRMS</sub> = 2x 180 A**  
**I<sub>TAVM</sub> = 2x 104 A**  
**V<sub>RRM</sub> = 2000-2200 V**

V <sub>RSM</sub> V <sub>DSM</sub> V	V <sub>RRM</sub> V <sub>DRM</sub> V	Type
2100	2000	MCC 94-20io1 B
2300	2200	MCC 94-22io1 B



Symbol	Test Conditions	Maximum Ratings		
I <sub>TRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	180	A	
I <sub>TAVM</sub>	T <sub>C</sub> = 85°C; 180° sine	104	A	
I <sub>TSM</sub>	T <sub>VJ</sub> = 45°C; V <sub>R</sub> = 0	1700 1800	A A	
	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)			
	T <sub>VJ</sub> = T <sub>VJM</sub> V <sub>R</sub> = 0	1540 1640	A A	
	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)			
j <sup>2</sup> dt	T <sub>VJ</sub> = 45°C V <sub>R</sub> = 0	14450 13500	A <sup>2</sup> s A <sup>2</sup> s	
	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)			
	T <sub>VJ</sub> = T <sub>VJM</sub> V <sub>R</sub> = 0	11850 11300	A <sup>2</sup> s A <sup>2</sup> s	
	t = 10 ms (50 Hz) t = 8.3 ms (60 Hz)			
(di/dt) <sub>cr</sub>	T <sub>VJ</sub> = T <sub>VJM</sub> f = 50 Hz, t <sub>p</sub> = 200 µs V <sub>D</sub> = 2/3 V <sub>DRM</sub> I <sub>G</sub> = 0.45 A, non repetitive, I <sub>T</sub> = I <sub>TAVM</sub> di <sub>G</sub> /dt = 0.45 A/µs	repetitive, I <sub>T</sub> = 250 A 500	150 A/µs	
(dv/dt) <sub>cr</sub>	T <sub>VJ</sub> = T <sub>VJM</sub> ; V <sub>DR</sub> = 2/3 V <sub>DRM</sub> R <sub>GK</sub> = ∞; method 1 (linear voltage rise)	1000	V/µs	
P <sub>GM</sub>	T <sub>VJ</sub> = T <sub>VJM</sub> I <sub>T</sub> = I <sub>TAVM</sub>	t <sub>p</sub> = 30 µs t <sub>p</sub> = 300 µs	10 5 0.5	W W W
P <sub>GAV</sub>			10	V
V <sub>RGM</sub>				
T <sub>VJ</sub>		-40 ... 125		°C
T <sub>VJM</sub>		125		°C
T <sub>stg</sub>		-40 ... 125		°C
V <sub>ISOL</sub>	50/60 Hz, RMS	t = 1 min	3000	V~
	I <sub>ISOL</sub> ≤ 1 mA	t = 1 s	3600	V~
M <sub>d</sub>	Mounting torque (M5)	2.5-4.0/22-35	Nm/lb.in.	
	Terminal connection torque (M5)	2.5-4.0/22-35	Nm/lb.in.	
Weight	Typical including screws	90	g	

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.  
 IXYS reserves the right to change limits, test conditions and dimensions



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### Features

- International standard package, JEDEC TO-240 AA
- Direct Copper Bonded Al<sub>2</sub>O<sub>3</sub> -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873
- Gate-cathode twin pins for version 1B

### Applications

- DC motor control
- Softstart AC motor controller
- Light, heat and temperature control

### Advantages

- Space and weight savings
- Simple mounting with two screws
- Improved temperature and power cycling
- Reduced protection circuits

Symbol	Test Conditions	Characteristic Values	
$I_{RRM}, I_{DRM}$	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	15	mA
$V_T$	$I_T = 300 \text{ A}; T_{VJ} = 25^\circ\text{C}$	1.74	V
$V_{TO}$	For power-loss calculations only ( $T_{VJ} = T_{VJM}$ )	0.85	V
$r_T$		3.2	$\text{m}\Omega$
$V_{GT}$	$V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	1.5	V
$I_{GT}$	$V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	100	mA
		200	mA
$V_{GD}$	$T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$	0.25	V
$I_{GD}$	$T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$	10	mA
$I_L$	$T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; t_p = 30 \mu\text{s}$ $di_G/dt = 0.45 \text{ A}/\mu\text{s}; I_G = 0.45 \text{ A}$	200	mA
$I_H$	$T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; R_{GK} = \infty$	150	mA
$t_{gd}$	$T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$ $di_G/dt = 0.45 \text{ A}/\mu\text{s}; I_G = 0.45 \text{ A}$	2	$\mu\text{s}$
$t_q$	$T_{VJ} = T_{VJM}; V_R = 100 \text{ V}; V_D = 2/3 V_{DRM}; t_p = 200 \mu\text{s}$ $dv/dt = 20 \text{ V}/\mu\text{s}; I_T = 150 \text{ A}; -di/dt = 10 \text{ A}/\mu\text{s}$	typ. 185	$\mu\text{s}$
$Q_s$	$T_{VJ} = T_{VJM}$ $-di/dt = 6 \text{ A}/\mu\text{s}; I_T = 50 \text{ A}$	170	$\mu\text{C}$
$I_{RM}$		45	A
$R_{thJC}$	per thyristor; DC current	0.22	K/W
	per module	0.11	K/W
$R_{thJK}$	per thyristor; DC current	0.42	K/W
	per module	0.21	K/W
$d_s$	Creeping distance on surface	DataSheet4U.com 12.7	mm
$d_A$	Creepage distance in air	9.6	mm
$a$	Maximum allowable acceleration	50	$\text{m}/\text{s}^2$

Optional accessories for module-type MCC 94 version 1 B

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red

Type **ZY 200L** (L = Left for pin pair 4/5)      } UL 758, style 1385,

Type **ZY 200R** (R = right for pin pair 6/7)      } CSA class 5851, guide 460-1-1

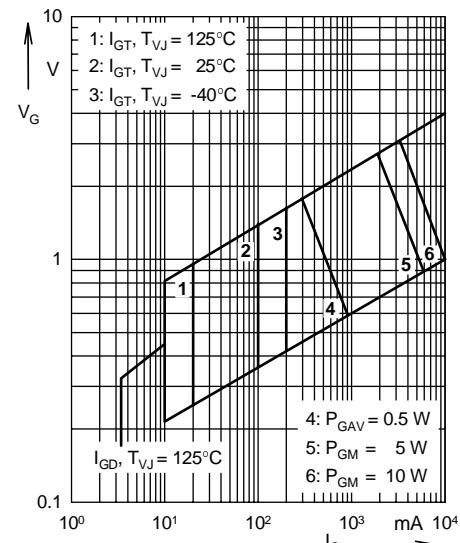


Fig. 1 Gate trigger characteristics

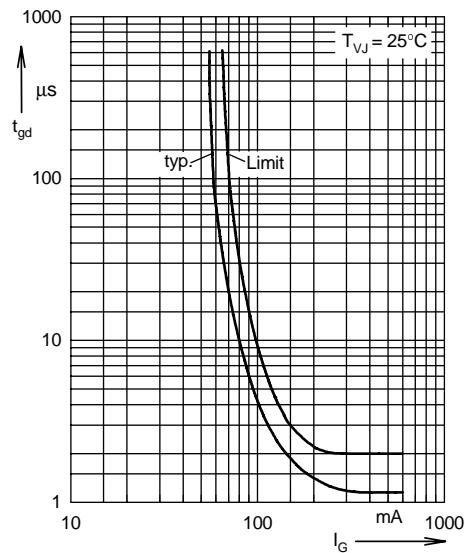
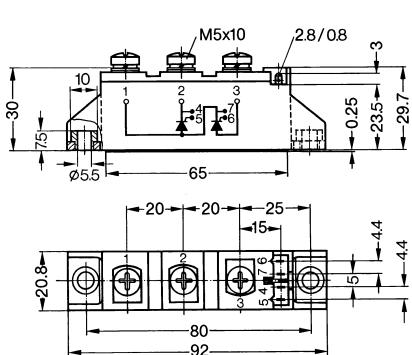


Fig. 2 Gate trigger delay time

#### Dimensions in mm (1 mm = 0.0394")



#### $R_{thJC}$ for various conduction angles d:

d	$R_{thJC}$ (K/W)
DC	0.22
180°	0.23
120°	0.25
60°	0.27
30°	0.28

#### Constants for $Z_{thJC}$ calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0066	0.0019
2	0.0678	0.0477
3	0.1456	0.344

#### $R_{thJK}$ for various conduction angles d:

d	$R_{thJK}$ (K/W)
DC	0.42
180°	0.43
120°	0.45
60°	0.47
30°	0.48

#### Constants for $Z_{thJK}$ calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0066	0.0019
2	0.0678	0.0477
3	0.1456	0.344
4	0.2	1.32